



# PJS6403

## 30V P-Channel Enhancement Mode MOSFET

**Voltage**

**-30 V**

**Current**

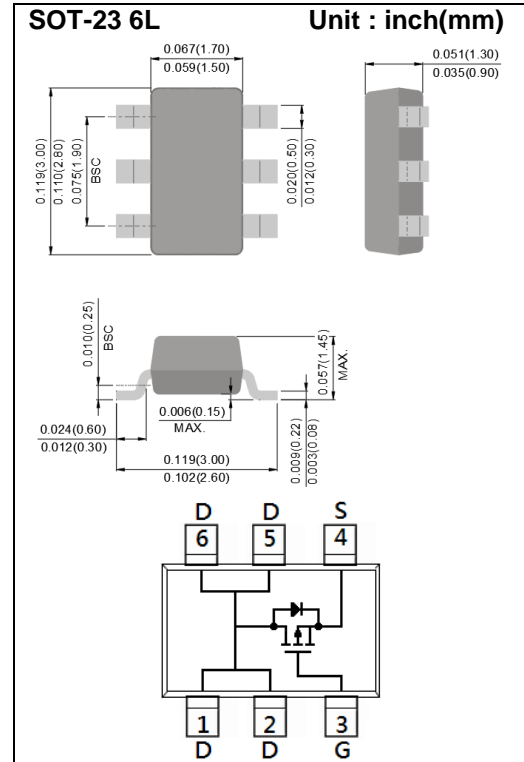
**-6.4A**

### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-4A < 32m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-2A < 46m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0005 ounces, 0.014 grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER  |                                 | SYMBOL          | LIMIT   | UNITS                |
|--|---------------------------------|-----------------|---------|----------------------|
| Drain-Source Voltage                             |                                 | $V_{DS}$        | -30     | V                    |
| Gate-Source Voltage                              |                                 | $V_{GS}$        | +20     |                      |
| Continuous Drain Current <sup>(Note 4)</sup>     |                                 | $I_D$           | -6.4    | A                    |
| Pulsed Drain Current <sup>(Note 1,3)</sup>       |                                 | $I_{DM}$        | -46     |                      |
| Power Dissipation                                | $T_a=25^\circ\text{C}$          | $P_D$           | 2       | W                    |
|  | Derate above $25^\circ\text{C}$ |                 | 16      | mW/ $^\circ\text{C}$ |
| Operating Junction and Storage Temperature Range |                                 | $T_J, T_{STG}$  | -55~150 | $^\circ\text{C}$     |
| Typical Thermal Resistance                       |                                 | $R_{\theta JA}$ | 62.5    | $^\circ\text{C/W}$   |
| - Junction to Ambient <sup>(Note 5)</sup>        |                                 |                 |         |                      |



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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER   | SYMBOL              | TEST CONDITION   | MIN. | TYP.  | MAX. | UNITS |
|---|---------------------|--|------|-------|------|-------|
| <b>Static</b>   |                     |  |      |       |      |       |
| Drain-Source Breakdown Voltage                        | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA  | -30  | -     | -    | V     |
| Gate Threshold Voltage                                | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA  | -1   | -1.6  | -2.5 |       |
| Drain-Source On-State Resistance                      | R <sub>DS(on)</sub> | V <sub>GS</sub> =-10V, I <sub>D</sub> =-4A   | -    | 27    | 32   | mΩ    |
|   |                     | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2A  | -    | 38    | 46   |       |
| Zero Gate Voltage Drain Current                       | I <sub>DSS</sub>    | V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V   | -    | -     | -1   | uA    |
| Gate-Source Leakage Current                           | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V   | -    | -     | ±100 | nA    |
| <b>Dynamic</b> (Note 6)                               |                     |  |      |       |      |       |
| Total Gate Charge                                     | Q <sub>g</sub>      | V <sub>DS</sub> =-15V, I <sub>D</sub> =-5A,<br>V <sub>GS</sub> =-4.5V (Note 2,3)                       | -    | 7.8   | -    | nC    |
| Gate-Source Charge                                    | Q <sub>gs</sub>     |  | -    | 2.7   | -    |       |
| Gate-Drain Charge                                     | Q <sub>gd</sub>     |  | -    | 2.8   | -    |       |
| Input Capacitance                                     | C <sub>iss</sub>    | V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,<br>f=1MHZ  | -    | 870   | -    | pF    |
| Output Capacitance                                    | C <sub>oss</sub>    |  | -    | 130   | -    |       |
| Reverse Transfer Capacitance                          | C <sub>rss</sub>    |  | -    | 93    | -    |       |
| Turn-On Delay Time                                    | t <sub>d(on)</sub>  | V <sub>DD</sub> =-15V, I <sub>D</sub> =-1A,<br>V <sub>GS</sub> =-10V,<br>R <sub>G</sub> =6Ω (Note 2,3) | -    | 6.5   | -    | ns    |
| Turn-On Rise Time                                     | t <sub>r</sub>      |  | -    | 8.8   | -    |       |
| Turn-Off Delay Time                                   | t <sub>d(off)</sub> |  | -    | 73    | -    |       |
| Turn-Off Fall Time                                    | t <sub>f</sub>      |  | -    | 44    | -    |       |
| <b>Drain-Source Diode</b>                             |                     |  |      |       |      |       |
| Maximum Continuous Drain-Source Diode Forward Current | I <sub>S</sub>      | ---  | -    | -     | -2   | A     |
| Diode Forward Voltage                                 | V <sub>SD</sub>     | I <sub>S</sub> =-1A, V <sub>GS</sub> =0V   |      | -0.75 | -1   | V     |

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing



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## TYPICAL CHARACTERISTIC CURVES

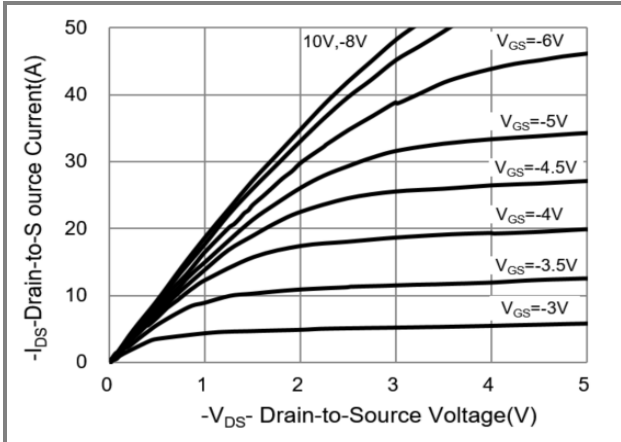


Fig.1 On-Region Characteristics

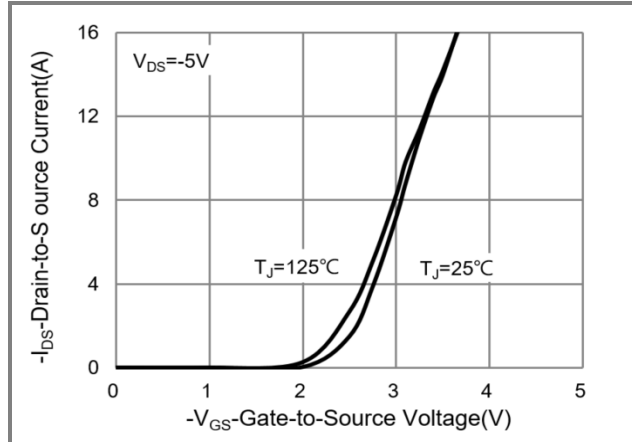


Fig.2 Transfer Characteristics

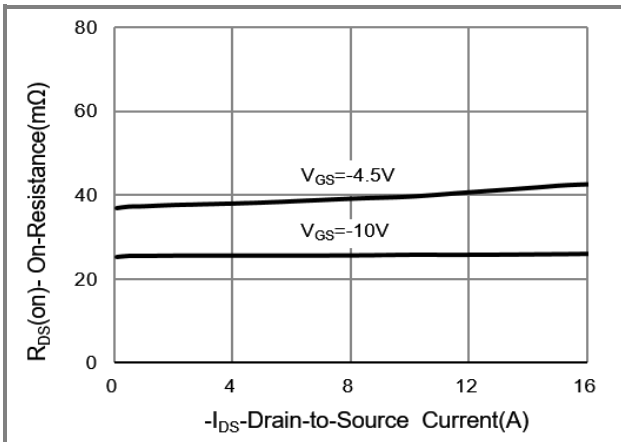


Fig.3 On-Resistance vs. Drain Current

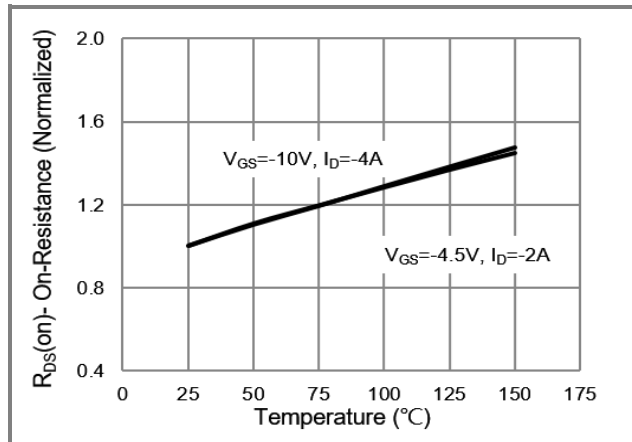


Fig.4 On-Resistance vs. Junction temperature

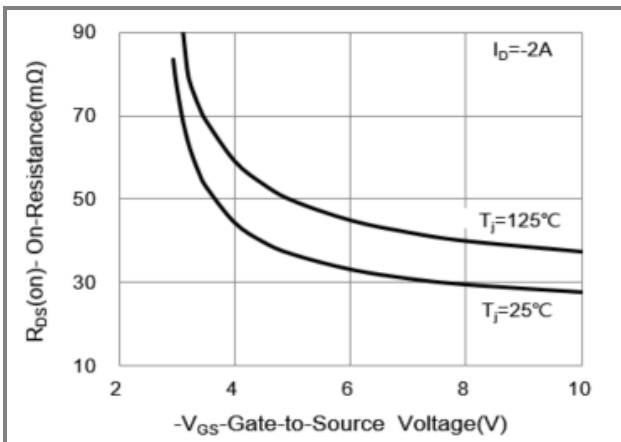


Fig.5 On-Resistance Variation with  $V_{GS}$

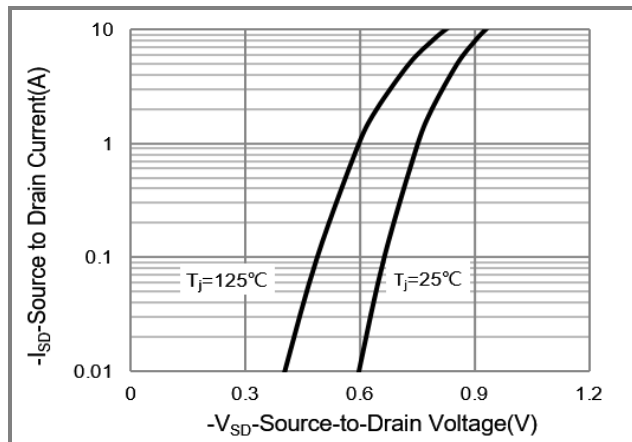


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

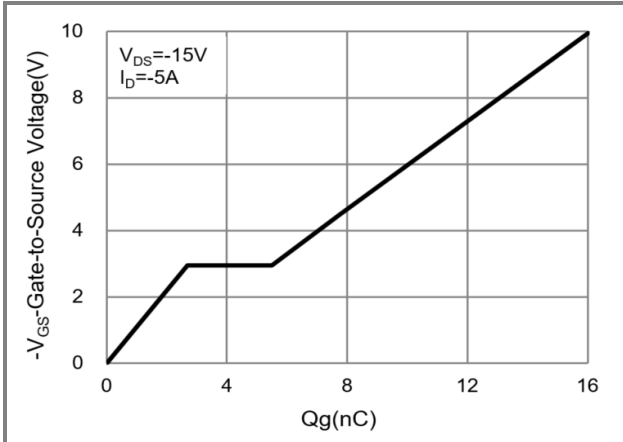


Fig.7 Gate-Charge Characteristics

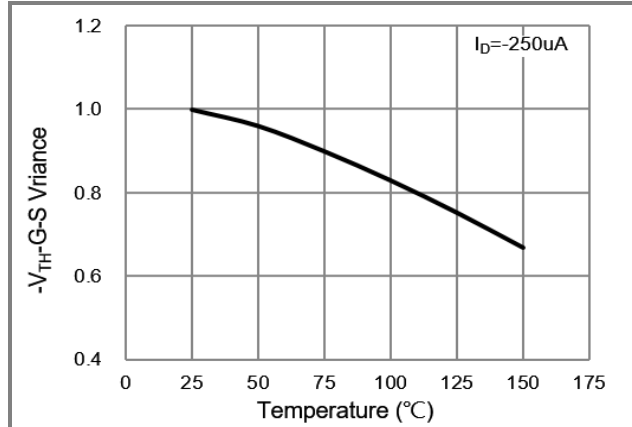


Fig.8 Threshold Voltage Variation with Temperature

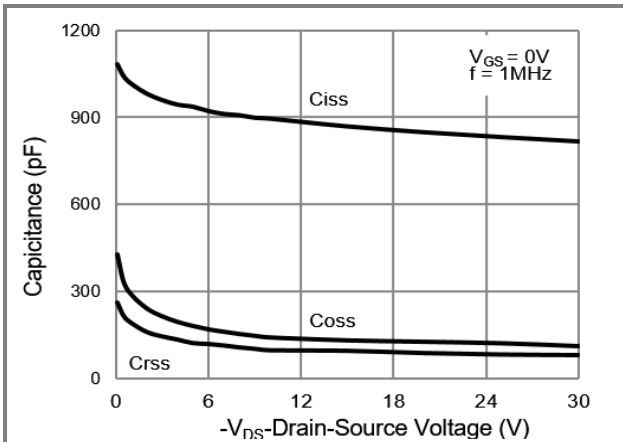


Fig.9 Capacitance vs. Drain-Source Voltage

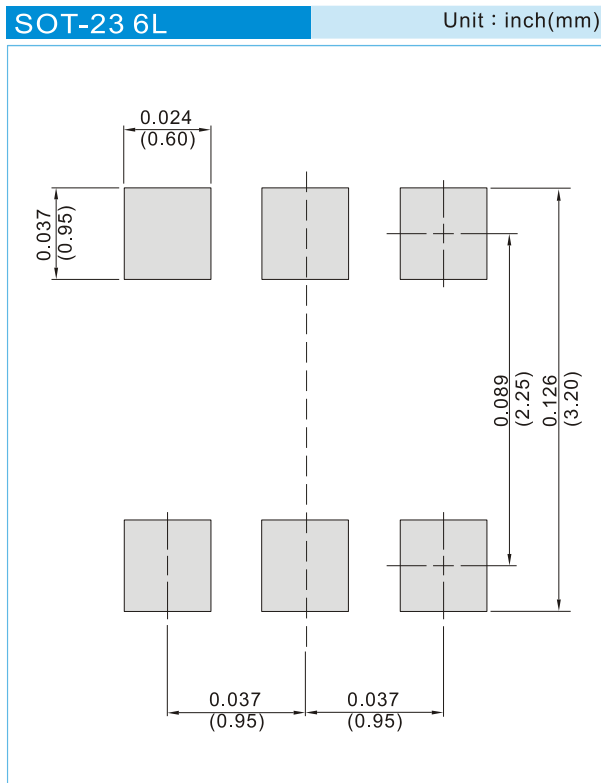


# PJS6403

## Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type     | Marking | Version                        |
|-----------------------|--------------|------------------|---------|--------------------------------|
| PJS6403_S1_00001      | SOT-23 6L    | 3K pcs / 7" reel | S03     | Halogen free<br>RoHS compliant |

## Mounting Pad Layout





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